

## Three quadrant triacs guaranteed commutation

## BTA216B series D, E and F

### GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a plastic envelope suitable for surface mounting, intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

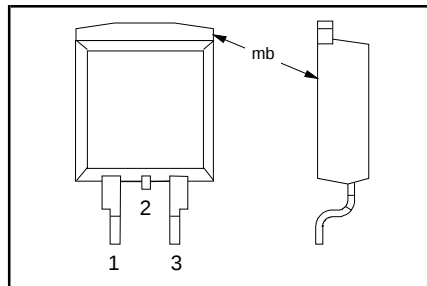
### QUICK REFERENCE DATA

| SYMBOL              | PARAMETER                                                                       | MAX.                                 | UNIT |
|---------------------|---------------------------------------------------------------------------------|--------------------------------------|------|
| $V_{\text{DRM}}$    | <b>BTA216B-<br/>BTA216B-<br/>BTA216B-</b><br>Repetitive peak off-state voltages | <b>600D<br/>600E<br/>600F</b><br>600 | V    |
| $I_{\text{T(RMS)}}$ | RMS on-state current                                                            | 16                                   | A    |
| $I_{\text{TSM}}$    | Non-repetitive peak on-state current                                            | 140                                  | A    |

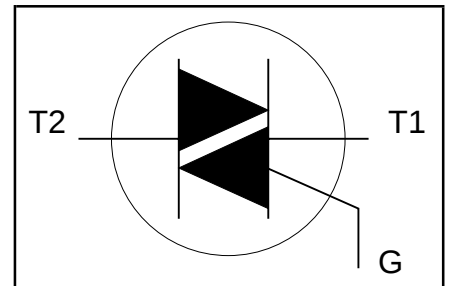
### PINNING - SOT404

| PIN | DESCRIPTION     |
|-----|-----------------|
| 1   | main terminal 1 |
| 2   | main terminal 2 |
| 3   | gate            |
| mb  | main terminal 2 |

### PIN CONFIGURATION



### SYMBOL



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL              | PARAMETER                                                    | CONDITIONS                                                                                                   | MIN. | MAX.             | UNIT             |
|---------------------|--------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------|------|------------------|------------------|
| $V_{\text{DRM}}$    | Repetitive peak off-state voltages                           |                                                                                                              | -    | 600 <sup>1</sup> | V                |
| $I_{\text{T(RMS)}}$ | RMS on-state current                                         | full sine wave;<br>$T_{\text{mb}} \leq 99^\circ\text{C}$                                                     | -    | 16               | A                |
| $I_{\text{TSM}}$    | Non-repetitive peak on-state current                         | full sine wave;<br>$T_j = 25^\circ\text{C}$ prior to surge                                                   | -    | 140              | A                |
|                     |                                                              | $t = 20\text{ ms}$                                                                                           | -    | 150              | A                |
|                     |                                                              | $t = 16.7\text{ ms}$                                                                                         | -    | 98               | A <sup>2</sup> s |
|                     |                                                              | $t = 10\text{ ms}$                                                                                           | -    | 100              | A/μs             |
| $I^2t$              | $I^2t$ for fusing                                            | $I_{\text{TM}} = 20\text{ A}; I_{\text{G}} = 0.2\text{ A};$<br>$dI_{\text{G}}/dt = 0.2\text{ A}/\mu\text{s}$ | -    |                  |                  |
| $dI_{\text{T}}/dt$  | Repetitive rate of rise of on-state current after triggering |                                                                                                              | -    |                  |                  |
| $I_{\text{GM}}$     | Peak gate current                                            |                                                                                                              | -    | 2                | A                |
| $P_{\text{GM}}$     | Peak gate power                                              |                                                                                                              | -    | 5                | W                |
| $P_{\text{G(AV)}}$  | Average gate power                                           | over any 20 ms period                                                                                        | -    | 0.5              | W                |
| $T_{\text{stg}}$    | Storage temperature                                          |                                                                                                              | -40  | 150              | °C               |
| $T_j$               | Operating junction temperature                               |                                                                                                              | -    | 125              | °C               |

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/μs.

## Three quadrant triacs guaranteed commutation

## BTA216B series D, E and F

### THERMAL RESISTANCES

| SYMBOL         | PARAMETER                                       | CONDITIONS                   | MIN. | TYP. | MAX. | UNIT |
|----------------|-------------------------------------------------|------------------------------|------|------|------|------|
| $R_{th\ j-mb}$ | Thermal resistance<br>junction to mounting base | full cycle                   | -    | -    | 1.2  | K/W  |
| $R_{th\ j-a}$  | Thermal resistance<br>junction to ambient       | half cycle                   | -    | -    | 1.7  | K/W  |
|                |                                                 | minimum footprint, FR4 board | -    | 55   | -    | K/W  |

### STATIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$  unless otherwise stated

| SYMBOL   | PARAMETER                         | CONDITIONS                                                                                                          | MIN.           | MAX.              |                |                | UNIT           |
|----------|-----------------------------------|---------------------------------------------------------------------------------------------------------------------|----------------|-------------------|----------------|----------------|----------------|
|          |                                   | <b>BTA216B-</b>                                                                                                     |                | <b>...D</b>       | <b>...E</b>    | <b>...F</b>    |                |
| $I_{GT}$ | Gate trigger current <sup>2</sup> | $V_D = 12\text{ V}; I_T = 0.1\text{ A}$<br>T2+ G+<br>T2+ G-<br>T2- G-                                               | -<br>-<br>-    | 5<br>5<br>5       | 10<br>10<br>10 | 25<br>25<br>25 | mA<br>mA<br>mA |
| $I_L$    | Latching current                  | $V_D = 12\text{ V}; I_{GT} = 0.1\text{ A}$<br>T2+ G+<br>T2+ G-<br>T2- G-                                            | -<br>-<br>-    | 15<br>25<br>25    | 25<br>30<br>30 | 30<br>40<br>40 | mA<br>mA<br>mA |
| $I_H$    | Holding current                   | $V_D = 12\text{ V}; I_{GT} = 0.1\text{ A}$                                                                          | -              | 15                | 25             | 30             | mA             |
|          |                                   |                                                                                                                     |                | <b>...D, E, F</b> |                |                |                |
| $V_T$    | On-state voltage                  | $I_T = 20\text{ A}$                                                                                                 | -              |                   | 1.5            |                | V              |
| $V_{GT}$ | Gate trigger voltage              | $V_D = 12\text{ V}; I_T = 0.1\text{ A}$<br>$V_D = 400\text{ V}; I_T = 0.1\text{ A};$<br>$T_j = 125\ ^\circ\text{C}$ | -<br>-<br>0.25 |                   | 1.5<br>-       |                | V<br>V         |
| $I_D$    | Off-state leakage current         | $V_D = V_{DRM(max)}; T_j = 125\ ^\circ\text{C}$                                                                     | -              |                   | 0.5            |                | mA             |

### DYNAMIC CHARACTERISTICS

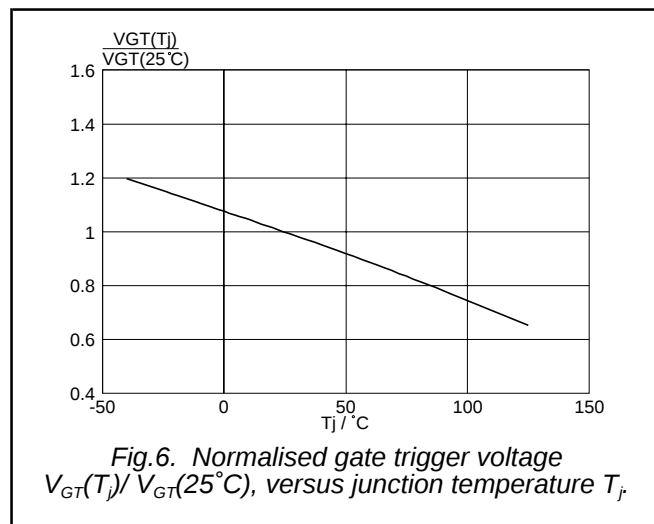
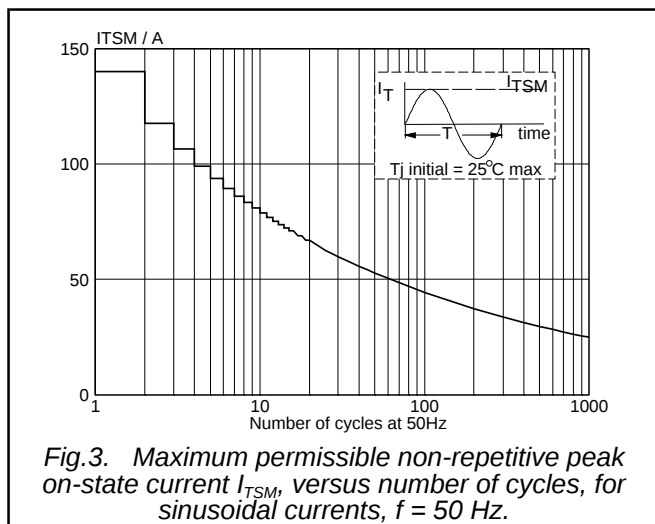
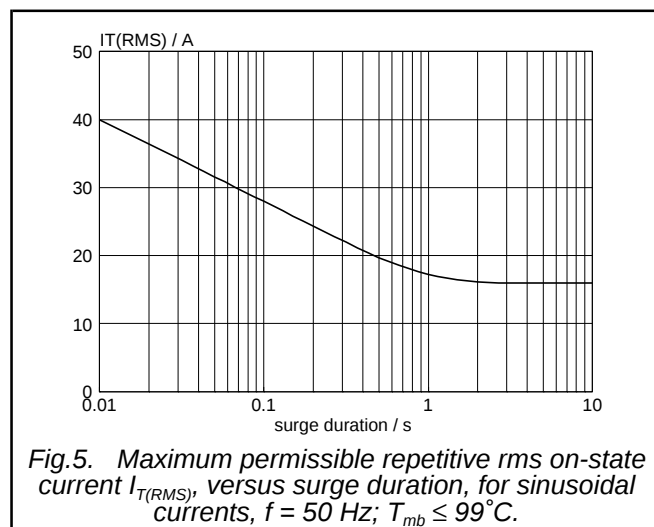
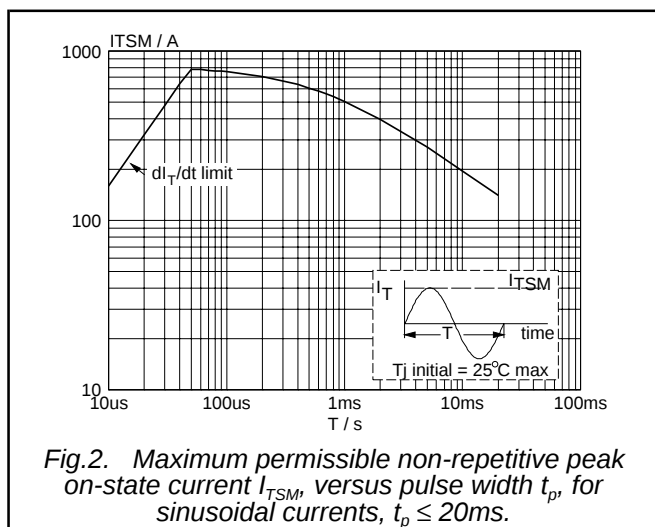
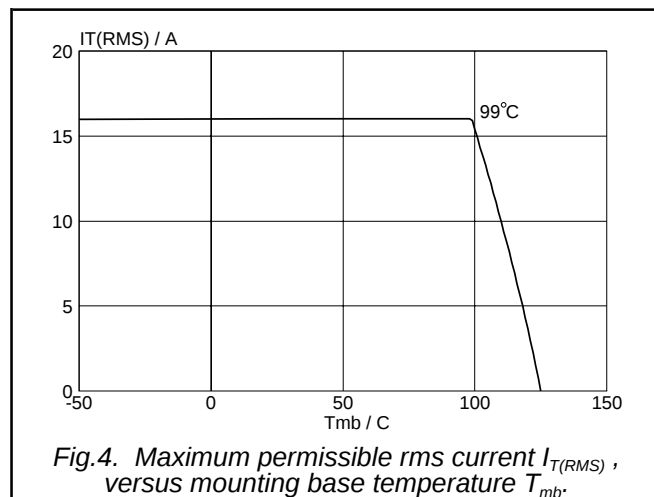
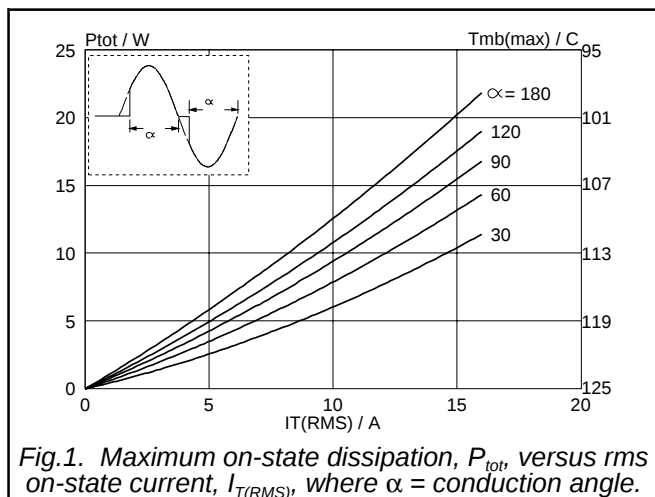
$T_j = 25\ ^\circ\text{C}$  unless otherwise stated

| SYMBOL        | PARAMETER                                         | CONDITIONS                                                                                                                                           | MIN.        |             |             | MAX. | UNIT             |
|---------------|---------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------|-------------|-------------|-------------|------|------------------|
|               |                                                   | <b>BTA216B-</b>                                                                                                                                      | <b>...D</b> | <b>...E</b> | <b>...F</b> |      |                  |
| $dV_D/dt$     | Critical rate of rise of<br>off-state voltage     | $V_{DM} = 67\% V_{DRM(max)};$<br>$T_j = 110\ ^\circ\text{C};$ exponential<br>waveform; gate open circuit                                             | 30          | 60          | 70          | -    | V/ $\mu\text{s}$ |
| $dI_{com}/dt$ | Critical rate of change of<br>commutating current | $V_{DM} = 400\text{ V}; T_j = 125\ ^\circ\text{C};$<br>$I_{T(RMS)} = 16\text{ A};$<br>$dV_{com}/dt = 10\text{ V}/\mu\text{s};$ gate<br>open circuit  | 2.5         | 6.2         | 18          | -    | A/ms             |
| $dI_{com}/dt$ | Critical rate of change of<br>commutating current | $V_{DM} = 400\text{ V}; T_j = 125\ ^\circ\text{C};$<br>$I_{T(RMS)} = 16\text{ A};$<br>$dV_{com}/dt = 0.1\text{ V}/\mu\text{s};$ gate<br>open circuit | 12          | 20          | 50          | -    | A/ms             |

<sup>2</sup> Device does not trigger in the T2-, G+ quadrant.

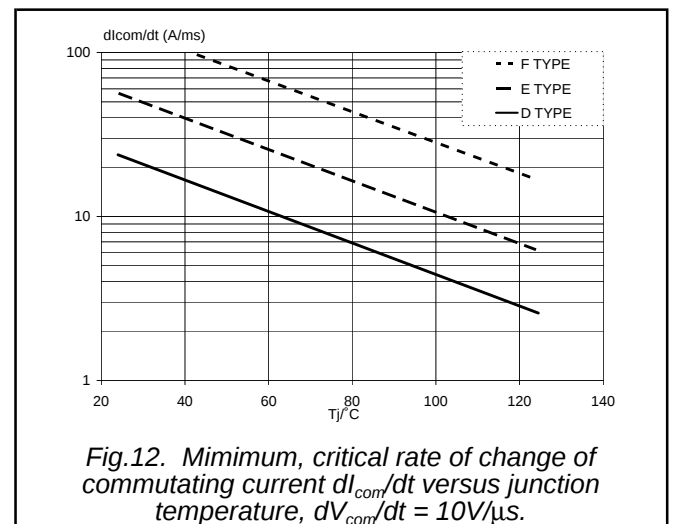
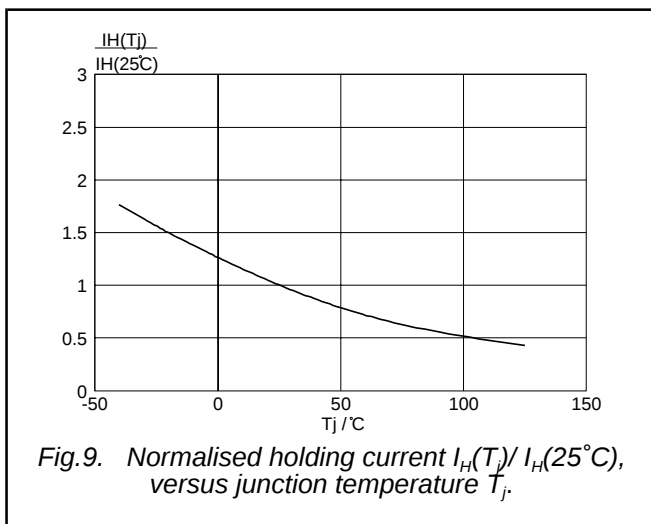
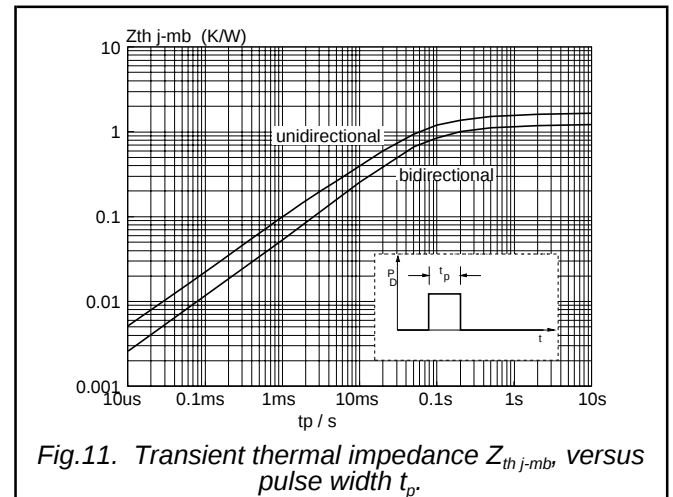
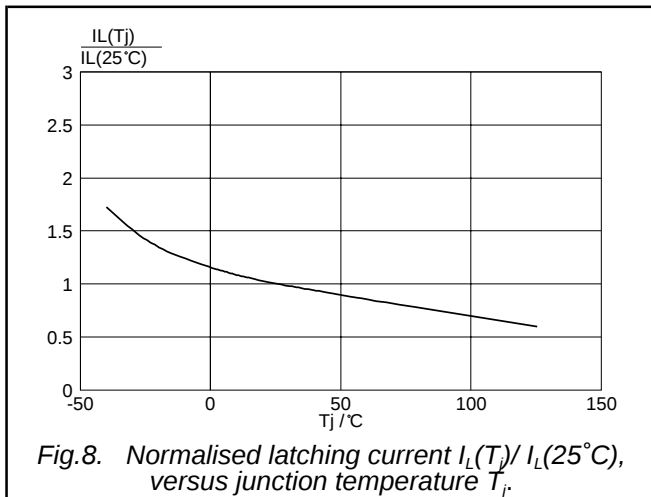
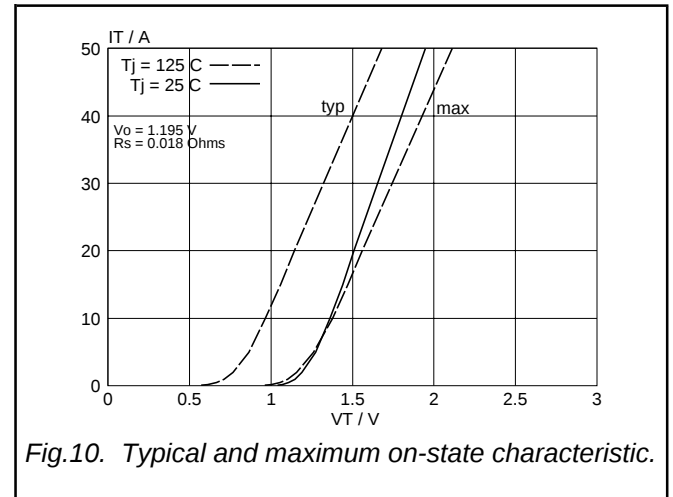
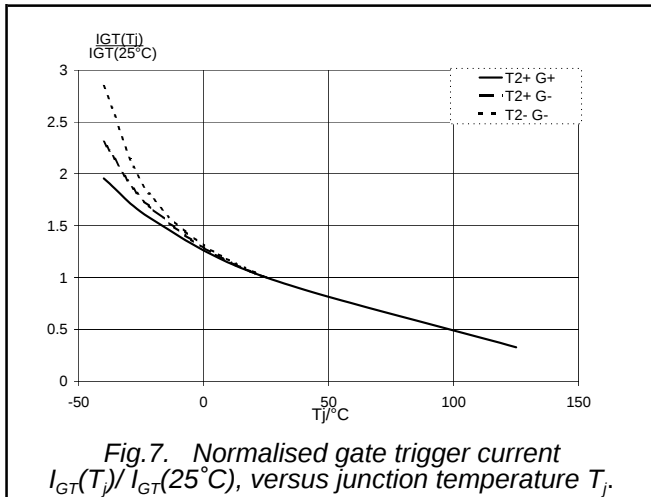
## Three quadrant triacs guaranteed commutation

## BTA216B series D, E and F



## Three quadrant triacs guaranteed commutation

## BTA216B series D, E and F



# Three quadrant triacs guaranteed commutation

BTA216B series D, E and F

## MECHANICAL DATA

Dimensions in mm

Net Mass: 1.4 g

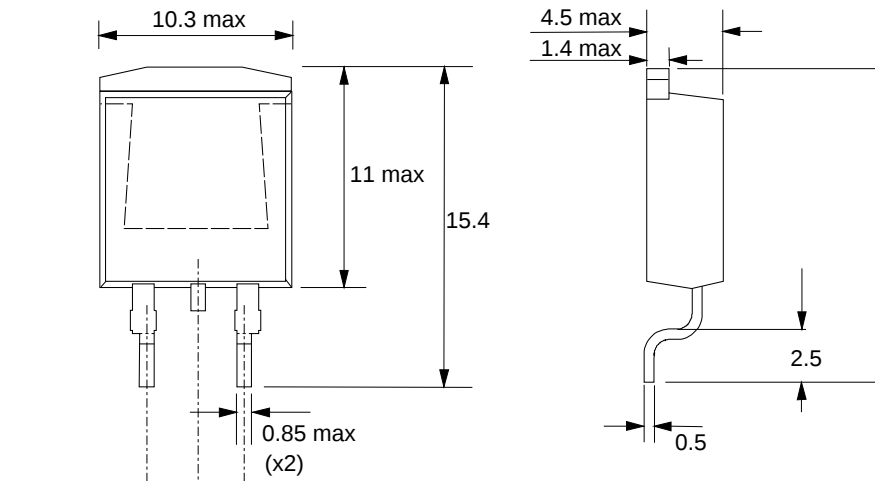


Fig.13. SOT404 : centre pin connected to mounting base.

## MOUNTING INSTRUCTIONS

Dimensions in mm

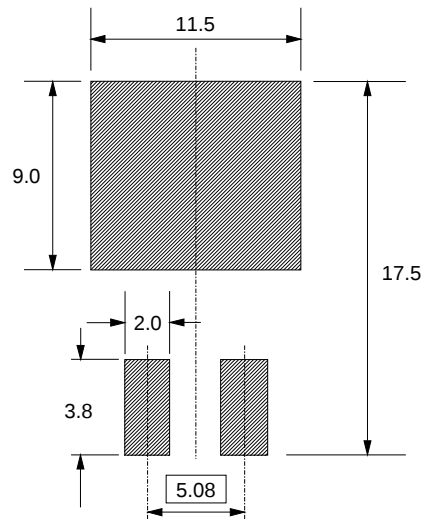


Fig.14. SOT404 : minimum pad sizes for surface mounting.

### Notes

1. Plastic meets UL94 V0 at 1/8".

## Three quadrant triacs guaranteed commutation

BTA216B series D, E and F

### DEFINITIONS

| DATA SHEET STATUS                                                                                                                                                                                                                                                                                                                                                                                                                                          |                             |                                                                                                                                                                                                                                                                                                                       |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| DATA SHEET STATUS <sup>3</sup>                                                                                                                                                                                                                                                                                                                                                                                                                             | PRODUCT STATUS <sup>4</sup> | DEFINITIONS                                                                                                                                                                                                                                                                                                           |
| Objective data                                                                                                                                                                                                                                                                                                                                                                                                                                             | Development                 | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice                                                                                                                            |
| Preliminary data                                                                                                                                                                                                                                                                                                                                                                                                                                           | Qualification               | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product                                     |
| Product data                                                                                                                                                                                                                                                                                                                                                                                                                                               | Production                  | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A |
| <b>Limiting values</b>                                                                                                                                                                                                                                                                                                                                                                                                                                     |                             |                                                                                                                                                                                                                                                                                                                       |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |                             |                                                                                                                                                                                                                                                                                                                       |
| <b>Application information</b>                                                                                                                                                                                                                                                                                                                                                                                                                             |                             |                                                                                                                                                                                                                                                                                                                       |
| Where application information is given, it is advisory and does not form part of the specification.                                                                                                                                                                                                                                                                                                                                                        |                             |                                                                                                                                                                                                                                                                                                                       |
| © Philips Electronics N.V. 2002                                                                                                                                                                                                                                                                                                                                                                                                                            |                             |                                                                                                                                                                                                                                                                                                                       |
| All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.                                                                                                                                                                                                                                                                                                                          |                             |                                                                                                                                                                                                                                                                                                                       |
| The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.                                                                       |                             |                                                                                                                                                                                                                                                                                                                       |

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

<sup>3</sup> Please consult the most recently issued datasheet before initiating or completing a design.

<sup>4</sup> The product status of the device(s) described in this datasheet may have changed since this datasheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.